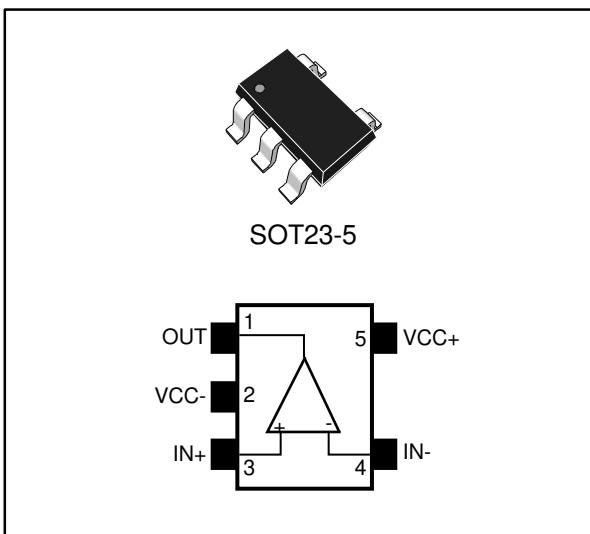


## Automotive rail-to-rail 1.8 V high-speed comparator

Datasheet - production data



## Features

- AEC-Q100 and Q003 qualified
- Extended temperature range:  
-40 °C to 150 °C
- Propagation delay: 38 ns
- Low current consumption: 73 µA
- Rail-to-rail inputs
- Push-pull outputs
- Supply operation from 1.8 to 5 V
- High ESD tolerance: 5 kV HBM, 300 V MM
- Latch-up immunity: 200 mA
- SMD package



## Related products

- TS3021 for standard temperature range  
(-40 °C to 125 °C)

## Applications

- Automotive
- Telecom
- Instrumentation
- Signal conditioning
- High-speed sampling systems
- Portable communication systems

## Description

The TS3021H single comparator features high-speed response time with rail-to-rail inputs. With a supply voltage specified from 2 to 5 V, this comparator can operate over a wide temperature range: -40 °C to 150 °C.

The TS3021H comparator offers micropower consumption as low as a few tens of microamperes thus providing an excellent ratio of power consumption current versus response time.

The TS3021H includes push-pull outputs and is available in the small SOT23-5 package.

## Contents

<b>1</b>	<b>Absolute maximum ratings and operating conditions .....</b>	<b>3</b>
<b>2</b>	<b>Electrical characteristics .....</b>	<b>4</b>
<b>3</b>	<b>Package information .....</b>	<b>15</b>
3.1	SOT23-5 package information .....	16
<b>4</b>	<b>Ordering information.....</b>	<b>17</b>
<b>5</b>	<b>Revision history .....</b>	<b>18</b>

# 1 Absolute maximum ratings and operating conditions

Table 1: Absolute maximum ratings (AMR)

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply voltage, V <sub>CC</sub> = (V <sub>CC+</sub> ) - (V <sub>CC-</sub> ) <sup>(1)</sup>	5.5	V
V <sub>ID</sub>	Differential input voltage <sup>(2)</sup>	±5	
V <sub>IN</sub>	Input voltage range	(V <sub>CC-</sub> ) - 0.3 to (V <sub>CC+</sub> ) + 0.3	
I <sub>IN</sub>	Input current <sup>(3)</sup>	10	mA
R <sub>thja</sub>	Thermal resistance junction-to-ambient <sup>(4)</sup>	250	°C/W
R <sub>thjc</sub>	Thermal resistance junction-to-case <sup>(4)</sup>	81	
T <sub>stg</sub>	Storage temperature	-65 to 160	°C
T <sub>j</sub>	Junction temperature	160	
T <sub>LEAD</sub>	Lead temperature (soldering 10 s)	260	
ESD	HBM: human body model <sup>(5)</sup>	5000	V
	CDM: charged device model <sup>(6)</sup>	1500	
	Latch-up immunity	200	mA

**Notes:**(1) All voltage values, except the differential voltage, are referenced to (V<sub>CC-</sub>)

(2) The magnitude of the input and output voltages must never exceed the supply rail ±0.3 V

(3) The input current must be limited by a resistor in series with the inputs.

(4) Short circuits can cause excessive heating. These values are typical

(5) Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.

(6) Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Table 2: Operating conditions

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply voltage	0 °C < Tamb < 150 °C	1.8 to 5
		-40 °C < Tamb < 150 °C	2 to 5
V <sub>icm</sub>	Common-mode input voltage range	-40 °C < Tamb < 85 °C	(V <sub>CC-</sub> ) - 0.2 to (V <sub>CC+</sub> ) + 0.2
		85 °C < Tamb < 150 °C	(V <sub>CC-</sub> ) to (V <sub>CC+</sub> )
T <sub>oper</sub>	Operating temperature range	-40 to 150	°C

## 2 Electrical characteristics

Table 3: Electrical characteristics at V<sub>CC</sub> = 2 V, Tamb = 25 °C, and full Vicm range  
(unless otherwise specified)

Symbol	Parameter	Test conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
V <sub>IO</sub>	Input offset voltage	Tamb		0.5	6	mV
		-40 °C < Tamb < 150 °C		0.5	7	
ΔV <sub>IO</sub> /ΔT	Input offset voltage drift	-40 °C < Tamb < 150 °C		3	20	μV/°C
I <sub>IO</sub>	Input offset current <sup>(2)</sup>	Tamb		1	20	nA
		-40 °C < Tamb < 150 °C			100	
I <sub>B</sub>	Input bias current <sup>(2)</sup>	Tamb		86	160	nA
		-40 °C < Tamb < 150 °C			300	
I <sub>CC</sub>	Supply current	No load, output high, Vicm = 0 V		73	90	μA
		No load, output high, Vicm = 0 V, -40 °C < Tamb < 150 °C			115	
		No load, output low, Vicm = 0 V		84	105	
		No load, output low, Vicm = 0 V, -40 °C < Tamb < 150 °C			125	
I <sub>SC</sub>	Short-circuit current	Source		9		mA
		Sink		10		
V <sub>OH</sub>	Output voltage high	I <sub>source</sub> = 1 mA	1.88	1.92		V
		-40 °C < Tamb < 150 °C	1.79			
V <sub>OL</sub>	Output voltage low	I <sub>sink</sub> = 1 mA		60	100	mV
		-40 °C < Tamb < 150 °C			170	
CMRR	Common-mode rejection ratio	0 < Vicm < 2 V		67		dB
SVR	Supply voltage rejection	ΔV <sub>CC</sub> = 2 to 5 V, Vicm = 0 V	58	73		
TP <sub>LH</sub>	Propagation delay, low to high output level <sup>(3)</sup>	Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV		38	60	ns
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV, -40 °C < Tamb < 150 °C			120	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV		48	75	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV, -40 °C < Tamb < 150 °C			140	

Symbol	Parameter	Test conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
$T_{PHL}$	Propagation delay, high to low output level <sup>(4)</sup>	Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV		40	60	ns
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV, -40 °C < Tamb < 150 °C			120	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV		49	75	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV, -40 °C < Tamb < 150 °C			140	
$T_F$	Fall time	f = 10 kHz, CL = 50 pF, RL = 10 kΩ, overdrive = 100 mV		8		
$T_R$	Rise time	f = 10 kHz, CL = 50 pF, RL = 10 kΩ, overdrive = 100 mV		9		

**Notes:**

<sup>(1)</sup>All values over the temperature range are guaranteed through correlation and simulation. No production test is performed at the temperature range limits.

<sup>(2)</sup>Maximum values include unavoidable inaccuracies of the industrial tests.

<sup>(3)</sup>Response time is measured 10%/90% of the final output value with the following conditions: inverting input voltage (IN-) = Vicm and non-inverting input voltage (IN+) moving from Vicm - 100 mV to Vicm + overdrive.

<sup>(4)</sup>Response time is measured 10%/90% of the final output value with the following conditions: Inverting input voltage (IN-) = Vicm and non-inverting input voltage (IN+) moving from Vicm + 100 mV to Vicm - overdrive.

**Table 4: Electrical characteristics at VCC = 3.3 V, Tamb = 25 °C, and full Vicm range  
(unless otherwise specified)**

Symbol	Parameter	Test conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
V <sub>IO</sub>	Input offset voltage	Tamb		0.2	6	mV
		-40 °C < Tamb < 150 °C		0.2	7	
ΔV <sub>IO</sub> /ΔT	Input offset voltage drift	-40 °C < Tamb < 150 °C		3	20	µV/°C
I <sub>IO</sub>	Input offset current <sup>(2)</sup>	Tamb		1	20	nA
		-40 °C < Tamb < 150 °C			100	
I <sub>IB</sub>	Input bias current <sup>(2)</sup>	Tamb		86	160	
		-40 °C < Tamb < 150 °C			300	
I <sub>CC</sub>	Supply current	No load, output high, Vicm = 0 V		75	90	µA
		No load, output high, Vicm = 0 V, -40 °C < Tamb < 150 °C			120	
		No load, output low, Vicm = 0 V		86	110	
		No load, output low, Vicm = 0 V, -40 °C < Tamb < 150 °C			125	
I <sub>SC</sub>	Short-circuit current	Source		26		mA
		Sink		24		
V <sub>OH</sub>	Output voltage high	I <sub>source</sub> = 1 mA	3.20	3.25		V
		-40 °C < Tamb < 150 °C	3.16			
V <sub>OL</sub>	Output voltage low	I <sub>sink</sub> = 1 mA		40	80	mV
		-40 °C < Tamb < 150 °C			120	
CMRR	Common-mode rejection ratio	0 < Vicm < 3.3 V		75		dB
SVR	Supply voltage rejection	ΔV <sub>CC</sub> = 2 to 5 V, Vicm = 0 V	58	73		
TP <sub>LH</sub>	Propagation delay, low to high output level <sup>(3)</sup>	Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV		39	65	ns
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV, -40 °C < Tamb < 150 °C			115	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV		50	85	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV, -40 °C < Tamb < 150 °C			145	

Symbol	Parameter	Test conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
$T_{PHL}$	Propagation delay, high to low output level <sup>(4)</sup>	Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV		41	65	ns
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV, -40 °C < Tamb < 150 °C			115	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV		51	80	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV, -40 °C < Tamb < 150 °C			145	
$T_F$	Fall time	f = 10 kHz, CL = 50 pF, RL = 10 kΩ, overdrive = 100 mV		5		
$T_R$	Rise time	f = 10 kHz, CL = 50 pF, RL = 10 kΩ, overdrive = 100 mV		7		

**Notes:**

<sup>(1)</sup>All values over the temperature range are guaranteed through correlation and simulation. No production test is performed at the temperature range limits.

<sup>(2)</sup>Maximum values include unavoidable inaccuracies of the industrial tests

<sup>(3)</sup>Response time is measured 10%/90% of the final output value with the following conditions: inverting input voltage (IN-) = Vicm and non-inverting input voltage (IN+) moving from Vicm - 100 mV to Vicm + overdrive.

<sup>(4)</sup>Response time is measured 10%/90% of the final output value with the following conditions: Inverting input voltage (IN-) = Vicm and non-inverting input voltage (IN+) moving from Vicm + 100 mV to Vicm - overdrive.

**Table 5: Electrical characteristics at VCC = 5 V, Tamb = 25 °C, and full Vicm range  
(unless otherwise specified)**

Symbol	Parameter	Test conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
V <sub>IO</sub>	Input offset voltage	Tamb		0.2	6	mV
		-40 °C < Tamb < 150 °C		0.2	7	
ΔV <sub>IO</sub> /ΔT	Input offset voltage drift	-40 °C < Tamb < 150 °C		3	20	µV/°C
I <sub>IO</sub>	Input offset current <sup>(2)</sup>	Tamb		1	20	nA
		-40 °C < Tamb < 150 °C			100	
I <sub>IB</sub>	Input bias current <sup>(2)</sup>	Tamb		86	160	
		-40 °C < Tamb < 150 °C			300	
I <sub>CC</sub>	Supply current	No load, output high, Vicm = 0 V		77	95	µA
		No load, output high, Vicm = 0 V, -40 °C < Tamb < 150 °C			125	
		No load, output low, Vicm = 0 V		89	115	
		No load, output low, Vicm = 0 V, -40 °C < Tamb < 150 °C			135	
I <sub>SC</sub>	Short-circuit current	Source		51		mA
		Sink		40		
V <sub>OH</sub>	Output voltage high	I <sub>source</sub> = 4 mA	4.80	4.84		V
		-40 °C < Tamb < 150 °C	4.68			
V <sub>OL</sub>	Output voltage low	I <sub>sink</sub> = 4 mA		130	180	mV
		-40 °C < Tamb < 150 °C			270	
CMRR	Common-mode rejection ratio	0 < Vicm < 5 V		79		dB
SVR	Supply voltage rejection	ΔV <sub>CC</sub> = 2 to 5 V, Vicm = 0 V	58	73		
TP <sub>LH</sub>	Propagation delay, low to high output level <sup>(3)</sup>	Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV		42	75	ns
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV, -40 °C < Tamb < 150 °C			120	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV		54	105	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV, -40 °C < Tamb < 150 °C			150	

Symbol	Parameter	Test conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
$T_{PHL}$	Propagation delay, high to low output level <sup>(4)</sup>	Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV		45	75	ns
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 100 mV, -40 °C < Tamb < 150 °C			120	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV		55	95	
		Vicm = 0 V, f = 10 kHz, CL = 50 pF, overdrive = 20 mV, -40 °C < Tamb < 150 °C			150	
$T_F$	Fall time	f = 10 kHz, CL = 50 pF, RL = 10 kΩ, overdrive = 100 mV		4		
$T_R$	Rise time	f = 10 kHz, CL = 50 pF, RL = 10 kΩ, overdrive = 100 mV		4		

**Notes:**

<sup>(1)</sup>All values over the temperature range are guaranteed through correlation and simulation. No production test is performed at the temperature range limits.

<sup>(2)</sup>Maximum values include unavoidable inaccuracies of the industrial tests

<sup>(3)</sup>Response time is measured 10%/90% of the final output value with the following conditions: inverting input voltage (IN-) = Vicm and non-inverting input voltage (IN+) moving from Vicm - 100 mV to Vicm + overdrive.

<sup>(4)</sup>Response time is measured 10%/90% of the final output value with the following conditions: Inverting input voltage (IN-) = Vicm and non-inverting input voltage (IN+) moving from Vicm + 100 mV to Vicm - overdrive.

Figure 1: Current consumption vs. supply voltage  
( $V_{ICM} = 0$  V, output high)

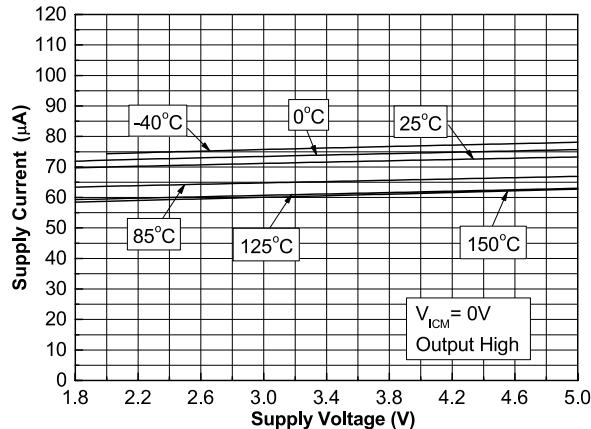


Figure 2: Current consumption vs. supply voltage  
( $V_{ICM} = V_{CC}$  output high)

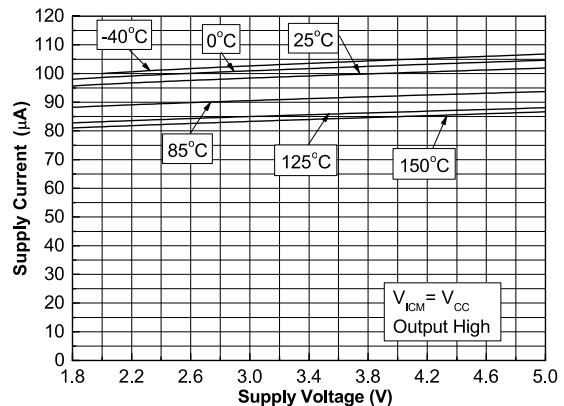


Figure 3: Current consumption vs. supply voltage  
( $V_{ICM} = 0$  V, output low)

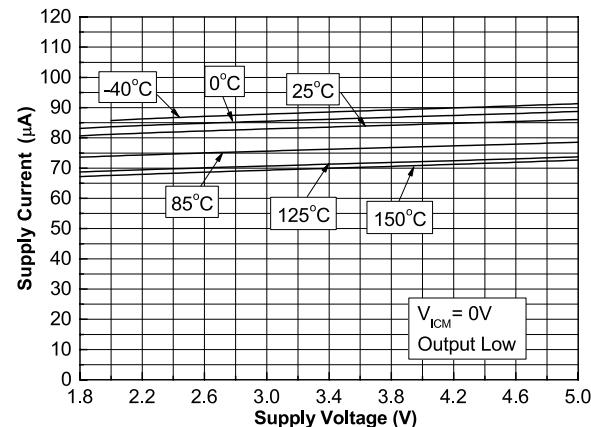


Figure 4: Current consumption vs. supply voltage  
( $V_{ICM} = V_{CC}$  output low)

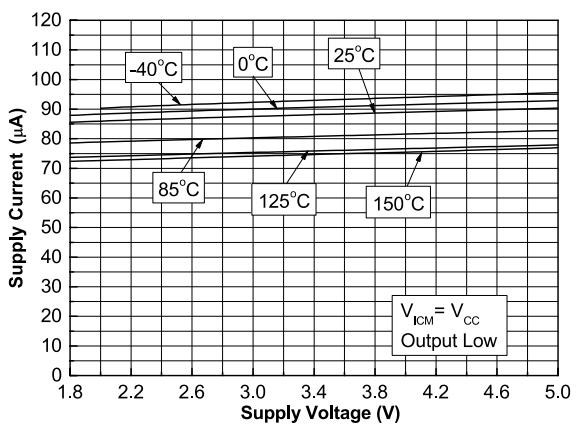


Figure 5: Output voltage vs. source current,  $V_{CC} = 2$  V

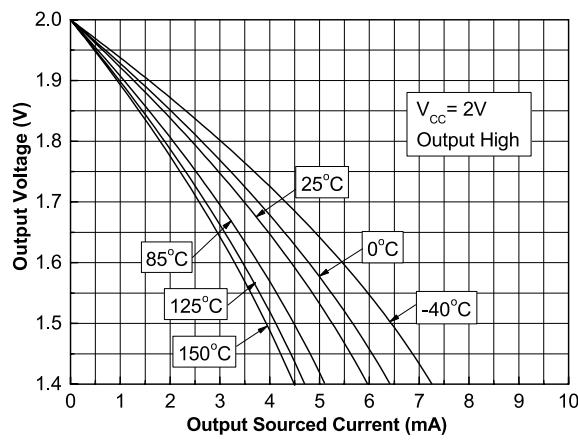


Figure 6: Output voltage vs. sink current,  $V_{CC} = 2$  V

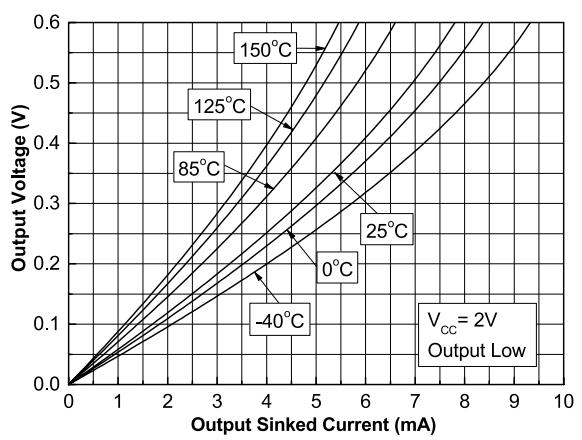


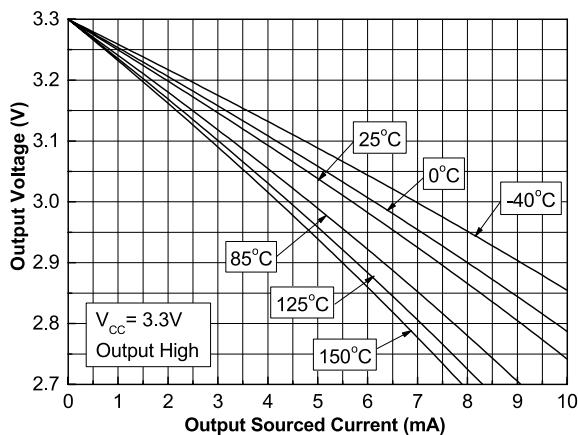
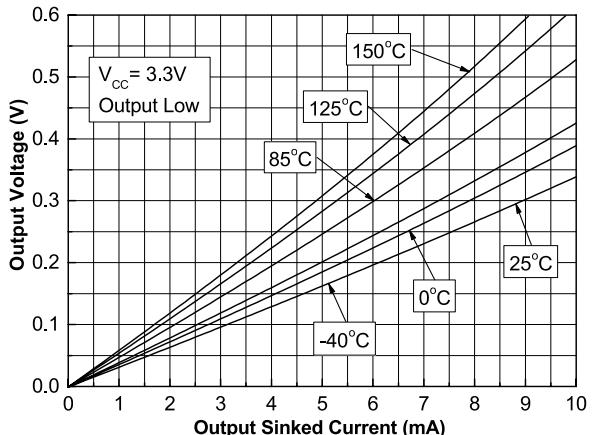
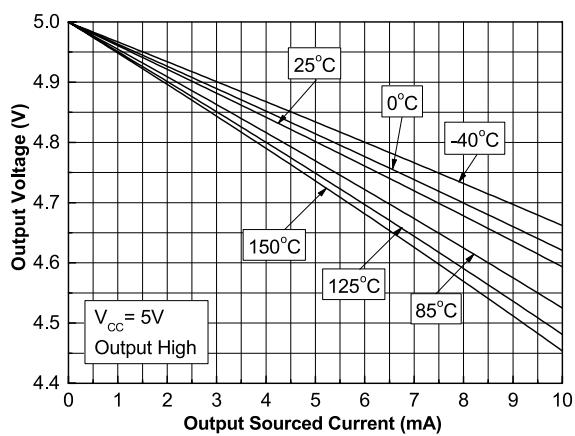
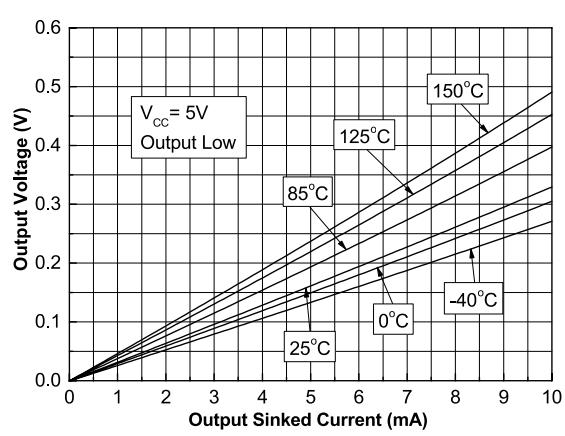
Figure 7: Output voltage vs. source current,  $V_{CC} = 3.3\text{ V}$ Figure 8: Output voltage vs. sink current,  $V_{CC} = 3.3\text{ V}$ Figure 9: Output voltage vs. source current,  $V_{CC} = 5\text{ V}$ Figure 10: Output voltage vs. sink current,  $V_{CC} = 5\text{ V}$ 

Figure 11: Input offset voltage vs. input common-mode voltage and temperature

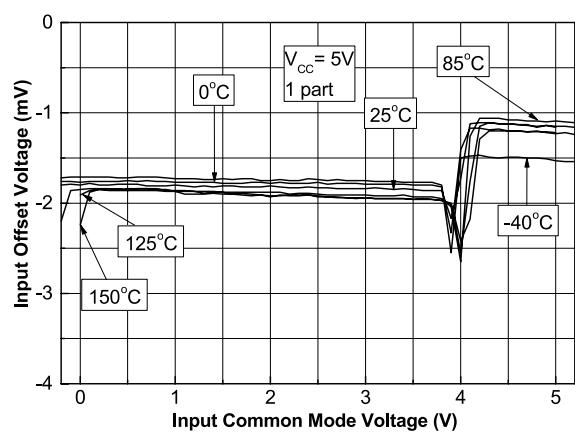
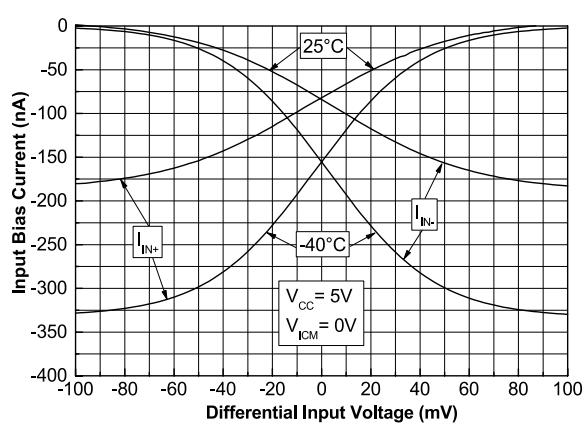


Figure 12: Input bias current vs. input differential voltage and temperature



## Electrical characteristics

TS3021H

Figure 13: Input bias current vs. input common-mode voltage

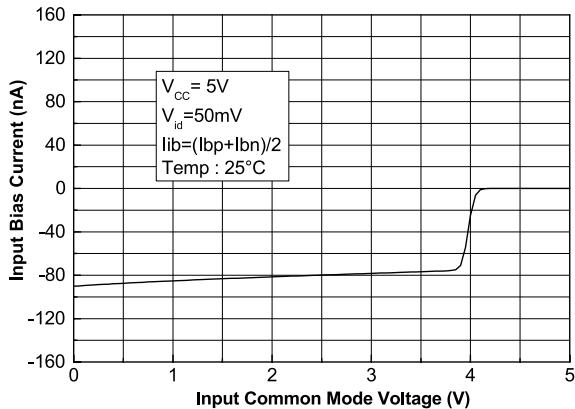


Figure 14: Input bias current vs. temperature

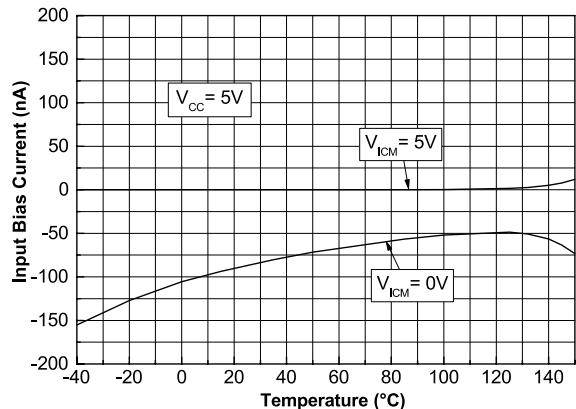


Figure 15: Current consumption vs. commutation frequency

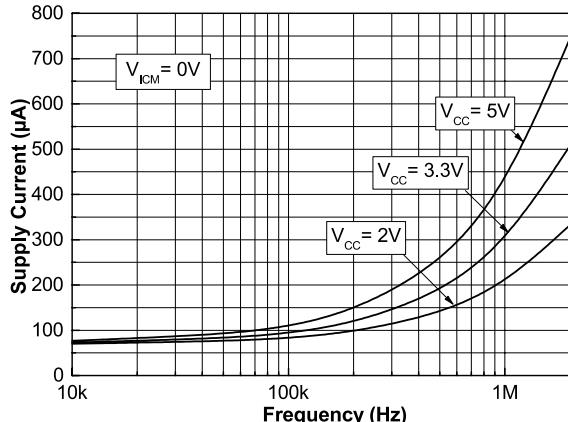


Figure 16: Propagation delay (HL) vs. overdrive at  $V_{CC} = 2V$ ,  $V_{ICM} = 0V$

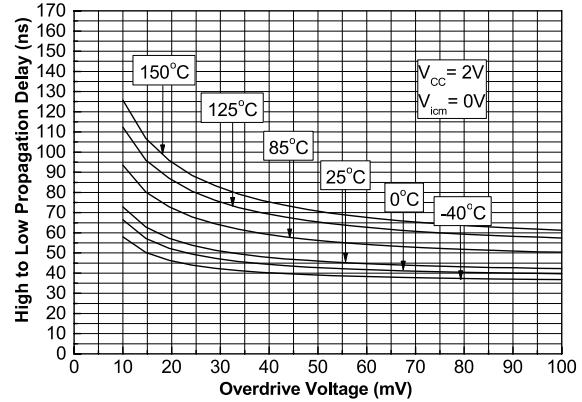


Figure 17: Propagation delay (HL) vs. overdrive at  $V_{CC} = 2V$ ,  $V_{ICM} = V_{CC}$

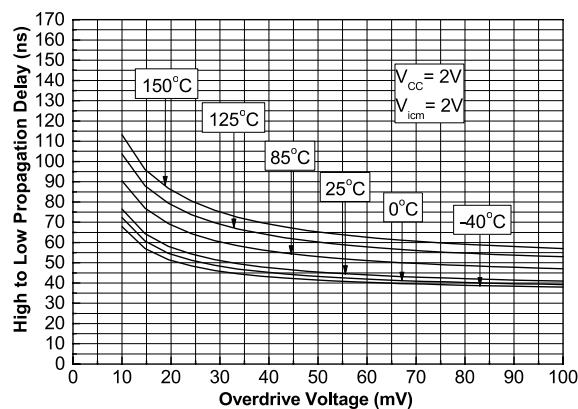


Figure 18: Propagation delay (LH) vs. overdrive at  $V_{CC} = 2V$ ,  $V_{ICM} = 0V$

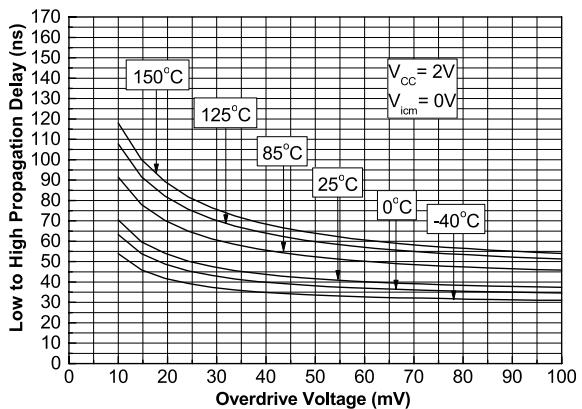


Figure 19: Propagation delay (LH) vs. overdrive at  $V_{cc} = 2\text{ V}$ ,  $V_{icm} = V_{cc}$

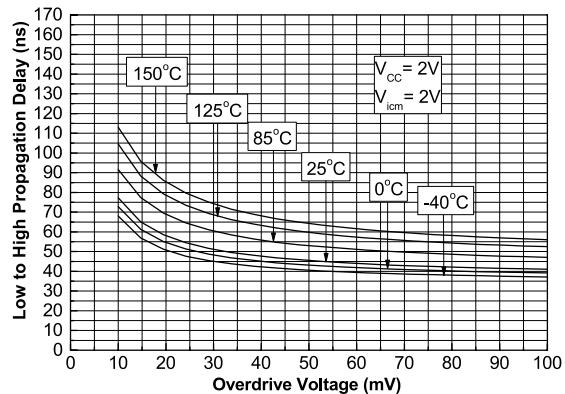


Figure 20: Propagation delay (HL) vs. overdrive at  $V_{cc} = 3.3\text{ V}$ ,  $V_{icm} = 0\text{ V}$

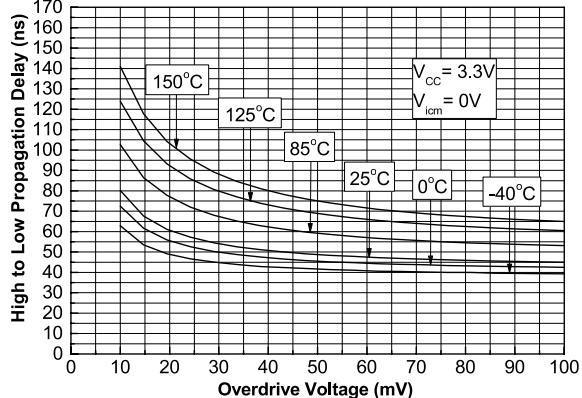


Figure 21: Propagation delay (HL) vs. overdrive at  $V_{cc} = 3.3\text{ V}$ ,  $V_{icm} = V_{cc}$

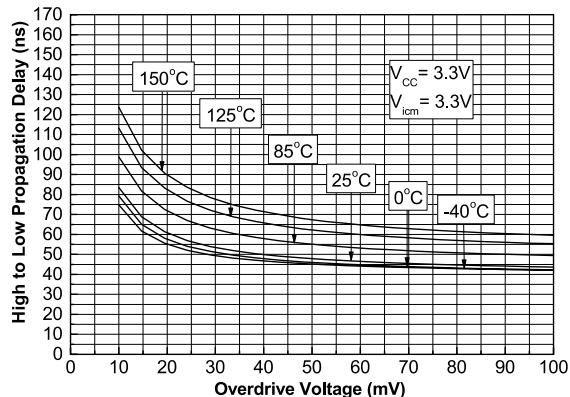


Figure 22: Propagation delay (LH) vs. overdrive at  $V_{cc} = 3.3\text{ V}$ ,  $V_{icm} = 0\text{ V}$

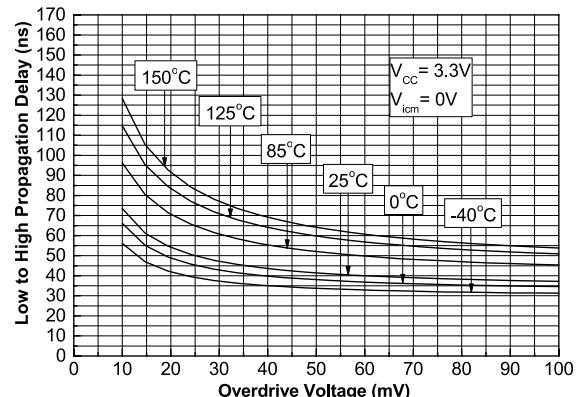


Figure 23: Propagation delay (LH) vs. overdrive at  $V_{cc} = 3.3\text{ V}$ ,  $V_{icm} = V_{cc}$

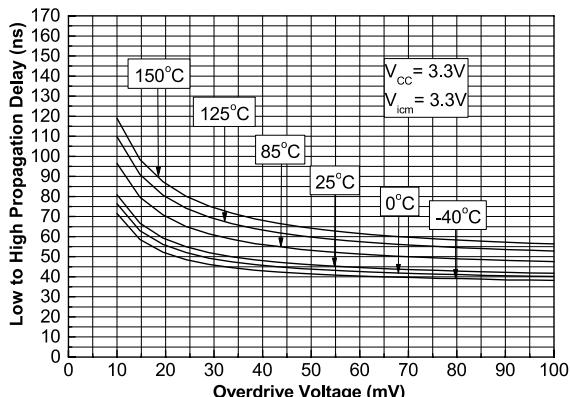


Figure 24: Propagation delay (HL) vs. overdrive at  $V_{cc} = 5\text{ V}$ ,  $V_{icm} = 0\text{ V}$

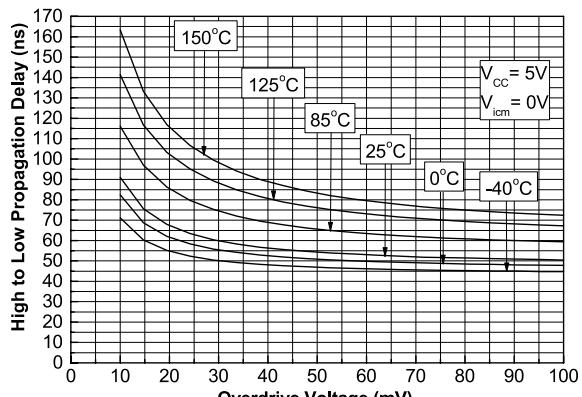


Figure 25: Propagation delay (HL) vs. overdrive at  $V_{CC} = 5\text{ V}$ ,  $V_{ICM} = V_{CC}$

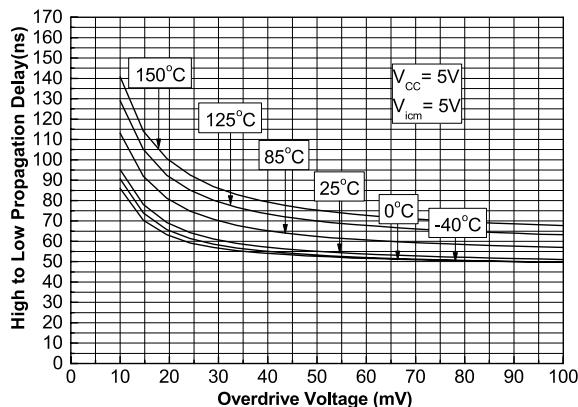


Figure 26: Propagation delay (LH) vs. overdrive at  $V_{CC} = 5\text{ V}$ ,  $V_{ICM} = 0\text{ V}$

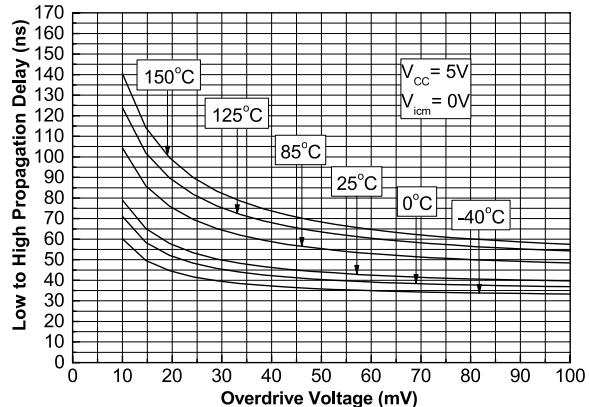


Figure 27: Propagation delay (LH) vs. overdrive at  $V_{CC} = 5\text{ V}$ ,  $V_{ICM} = V_{CC}$

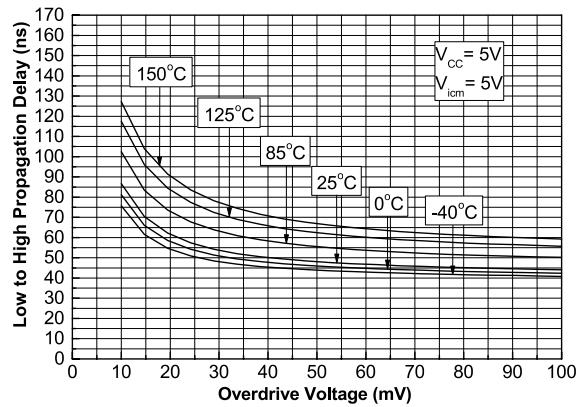


Figure 28: Propagation delay vs. temperature,  $V_{CC} = 5\text{ V}$ , overdrive = 100 mV

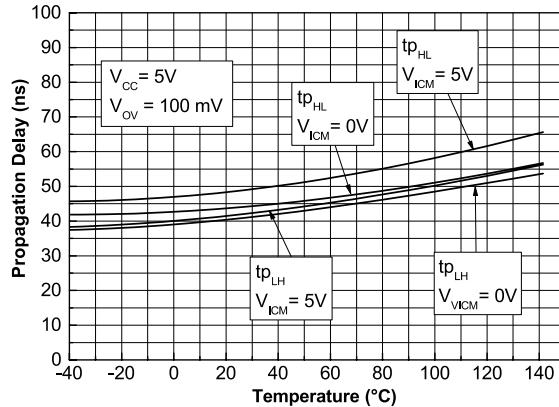
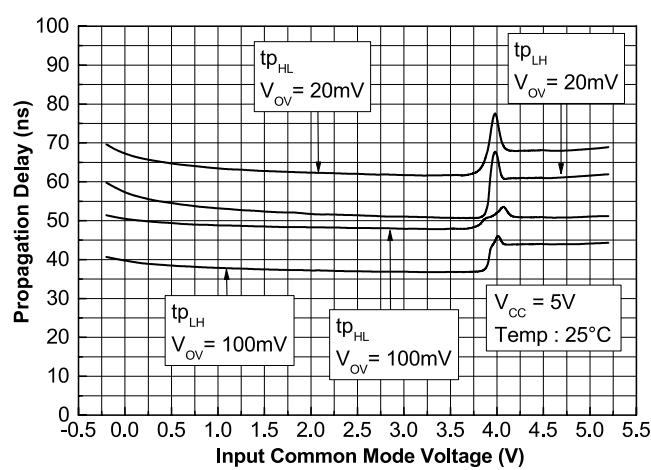


Figure 29: Propagation delay vs. common-mode voltage,  $V_{CC} = 5\text{ V}$



### 3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
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### 3.1 SOT23-5 package information

Figure 30: SOT23-5 package outline

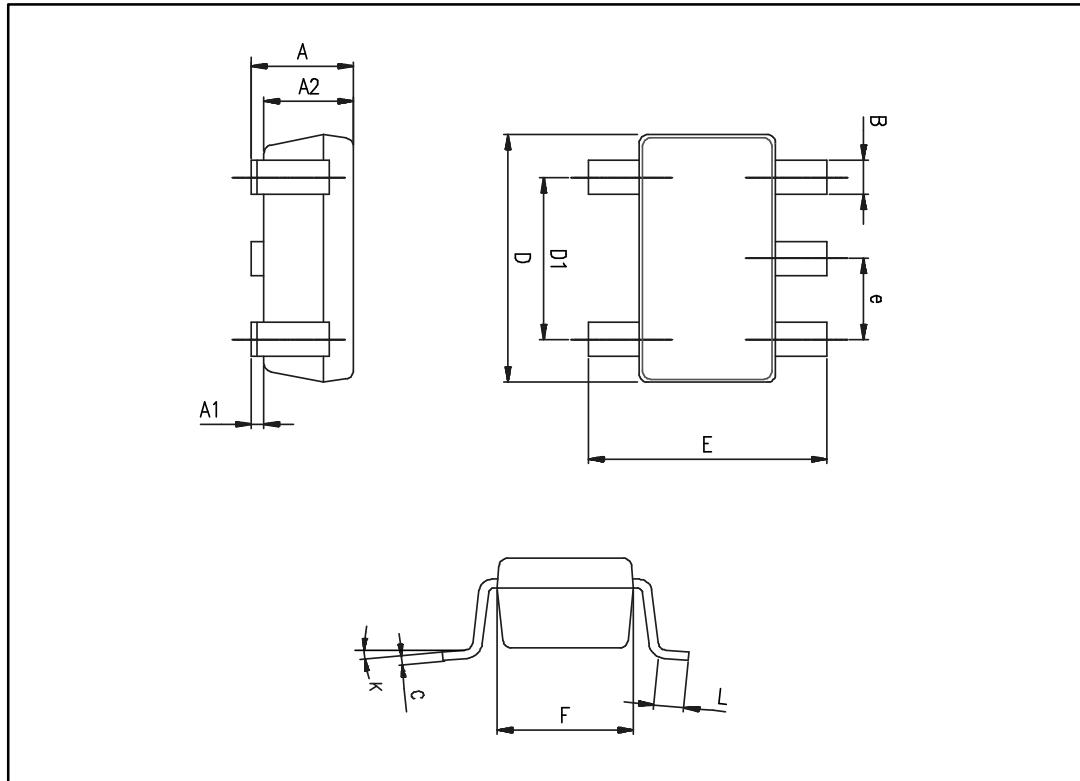


Table 6: SOT23-5 mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.90	1.20	1.45	0.035	0.047	0.057
A1			0.15			0.006
A2	0.90	1.05	1.30	0.035	0.041	0.051
B	0.35	0.40	0.50	0.014	0.016	0.020
C	0.09	0.15	0.20	0.004	0.006	0.008
D	2.80	2.90	3.00	0.110	0.114	0.118
D1		1.90			0.075	
e		0.95			0.037	
E	2.60	2.80	3.00	0.102	0.110	0.118
F	1.50	1.60	1.75	0.059	0.063	0.069
L	0.10	0.35	0.60	0.004	0.014	0.024
K	0 degrees		10 degrees	0 degrees		10 degrees

## 4 Ordering information

Table 7: Order codes

Order code	Temperature range	Package	Packaging	Marking
TS3021HIYLT <sup>(1)</sup>	-40 to 150 °C	SOT23-5	Tape and reel	K528

**Notes:**

<sup>(1)</sup>Qualified and characterized according to AEC-Q100 and Q003 or equivalent, advanced screening according to AEC-Q001 and Q 002 or equivalent.

## 5 Revision history

Table 8: Document revision history

Date	Version	Changes
13-Oct-2015	1	Initial release
24-Aug-2016	2	Updated document title (automotive qualified) Added AEC-Q100 and Q003 qualified in Features section <i>Table 1: "Absolute maximum ratings (AMR)":</i> removed ESD MM value. <i>Table 7: "Order codes":</i> updated footnote, product is now automotive qualified.

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